

Low Leakage Switching Diode

Features

- ◆Fast Switching Device (TRR <3.0uS)
- ◆Power Dissipation of 200mW
- ◆High Stability and High Reliability
- ◆Low reverse leakage

Mechanical Data

- ◆SOD-323 Small Outline Plastic Package
- ◆Polarity: Color band denotes cathode end
- ◆Mounting Position: Any



MARKING: PA

Maximum Ratings & Thermal Characteristics

(Ratings at 25°C ambient temperature unless otherwise specified.)

Parameters	Symbol	Value	Unit
Reverse Voltage	V_R	75	V
Peak Reverse Voltage	V_{RM}	100	V
Power Dissipation	P_d	200	mW
Operating junction temperature	T_j	-55-+150	°C
Storage temperature range	T_s	-55-+150	°C
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	625	°C/W
Continuous Forward Current	I_F	200	mA
Non-repetitive Peak Forward Surge Current @ $t_p=1\mu s$; $T_A=25^\circ C$	I_{FSM}	2.0	A

Note: FR-5 Board=1.0*0.75*0.062 in.

Electrical Characteristics

(Ratings at 25°C ambient temperature unless otherwise specified.)

Parameter	Symbols	Test Condition	Limits			Unit
			Min	Typ	Max	
Reverse Voltage	$V_{(BR)}$	$I_R=100\mu A$	75			V
Reverse Leakage Current	I_R	$V_R=75V$	---		5	nA
		$V_R=75V$ $T_j=150^\circ C$	---		80	nA
Forward Voltage	V_F	$I_F=1.0mA$	---		0.90	V
		$I_F=10mA$	---		1.00	
		$I_F=50mA$	---		1.10	
		$I_F=150mA$	---		1.25	
Reverse Recovery Time	T_{RR}	$I_F=I_R=10mA$ $R_L=100\Omega$	---		3.0	μS
Capacitance	C_T	$V_R=0V$, $f=1MHz$	---		2.0	pF

Typical Characteristics

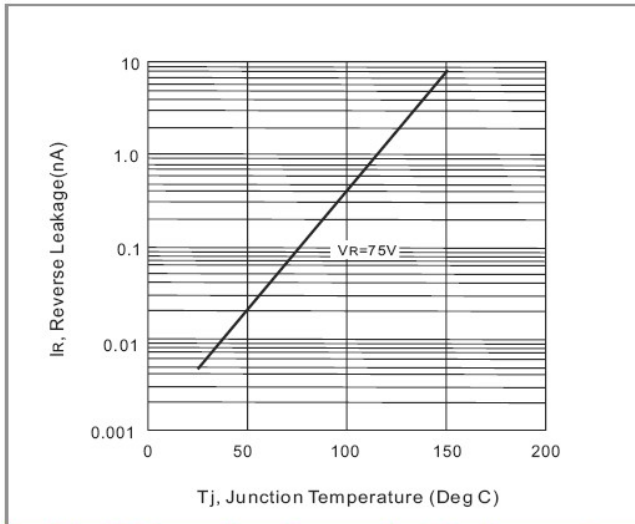


Fig. 1-Reverse Leakage vs. Junction Temperature

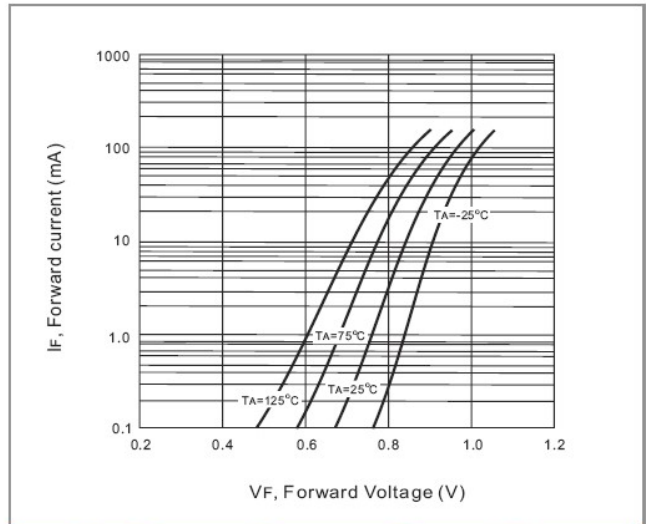


Fig. 2-Forward Current vs. Forward Voltage

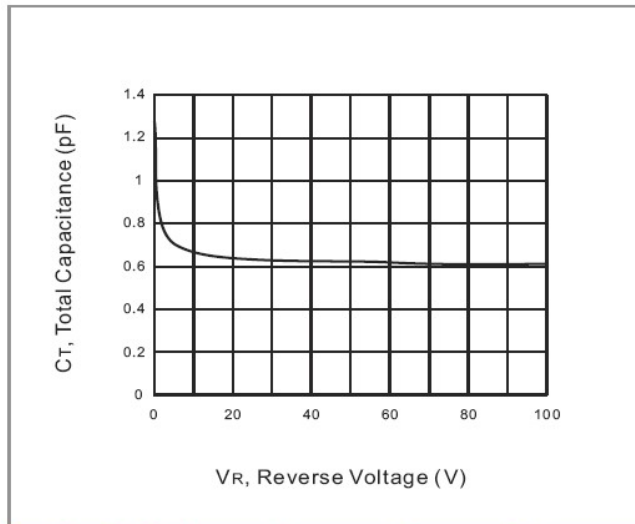
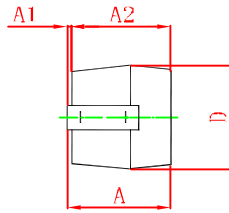
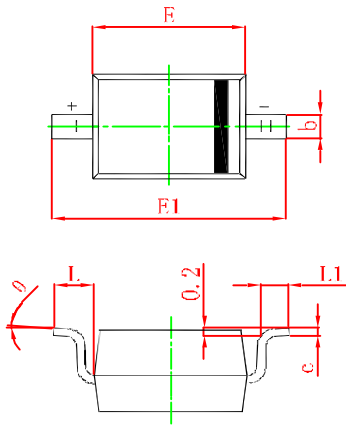


Fig. 3- Total capacitance vs. Reverse Voltage

Package Outline

SOD-323

Plastic surface mounted package



Symbol	Min.(mm)	Max.(mm)
A		1.000
A1	0.000	0.100
A2	0.800	0.900
b	0.250	0.350
c	0.080	0.150
D	1.200	1.400
E	1.600	1.800
E1	2.500	2.700
L	0.475REF	
L1	0.250	0.400
θ	0°	8°

Summary of Packing Options

Package	Packing Description	Packing Quantity	Industry Standard
SOD-323	Tape/Reel,7"reel	3000	EIA-481-1